

3W/CH Stereo Filter-less Class-D Audio Amplifier with Headphone Driver

Features

- Supply voltage range: 3.0 V to 5.5 V
- 10mA static operation current
- <1uA shutdown current
- 64 step DC volume control from -60 to +24dB
- Overload and thermal protection
- Loudspeaker Output power @ 10% THD+N
 - 1.75W/CH into 8Ω loudspeaker
 - 3.0W/CH into 4Ω loudspeaker
- Headphone Output power @ 1% THD+N
 - 60mW/CH into 32Ω loudspeaker
- High efficiency
 - 91% @ 8Ω, Po,10% THD+N
 - 84% @ 4Ω, Po,10% THD+N

- Portable multimedia devices
- Mobile phone

Description

The AD52652 is a stereo, filter-less class-D audio amplifier with class-AB headphone driver, and the built-in 64-steps DC volume controller is for both class-D and headphone amplifier. Operating with 5.0V power supply, it delivers 3.0W/CH power into 4Ω loudspeaker within 10% THD+N or 60mW/CH power into 32Ω headphone within 1% THD+N.

The AD52652 is packaged as SSOP-24(150mil) is a stereo audio amplifier with high efficiency, which leads to longer battery life, less heat sink, smaller board size, lower system cost, and suitable for the notebook, and portable multimedia devices.

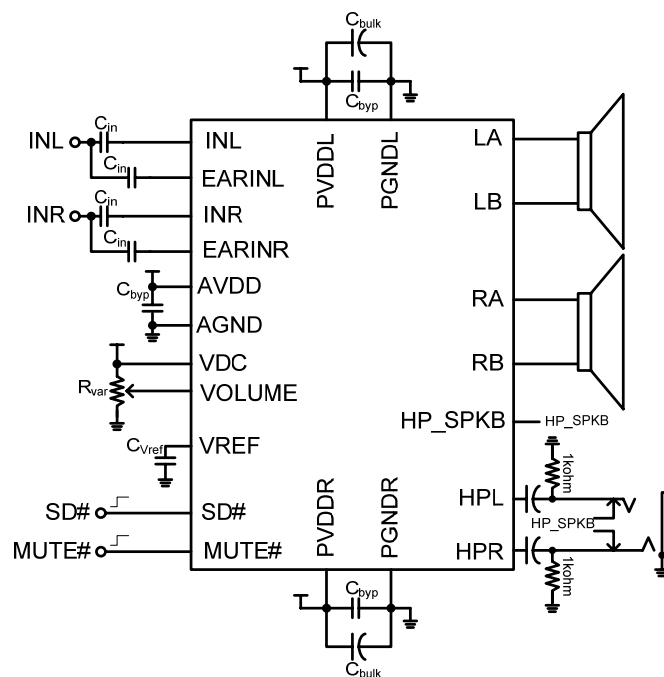
Applications

- Monitor audio

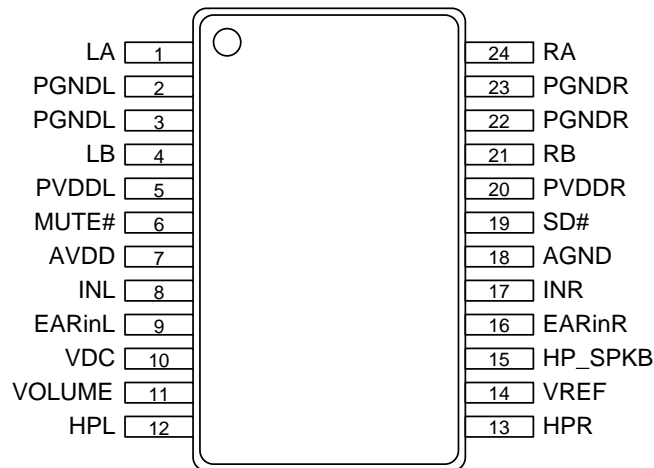
Ordering Information

Product ID	Package	Packing	Comments
AD52652-ST24NAT	SSOP-24L 150mil	56 Units / Tube 100 Tubes / Small BOX	Green

Typical Application Circuit



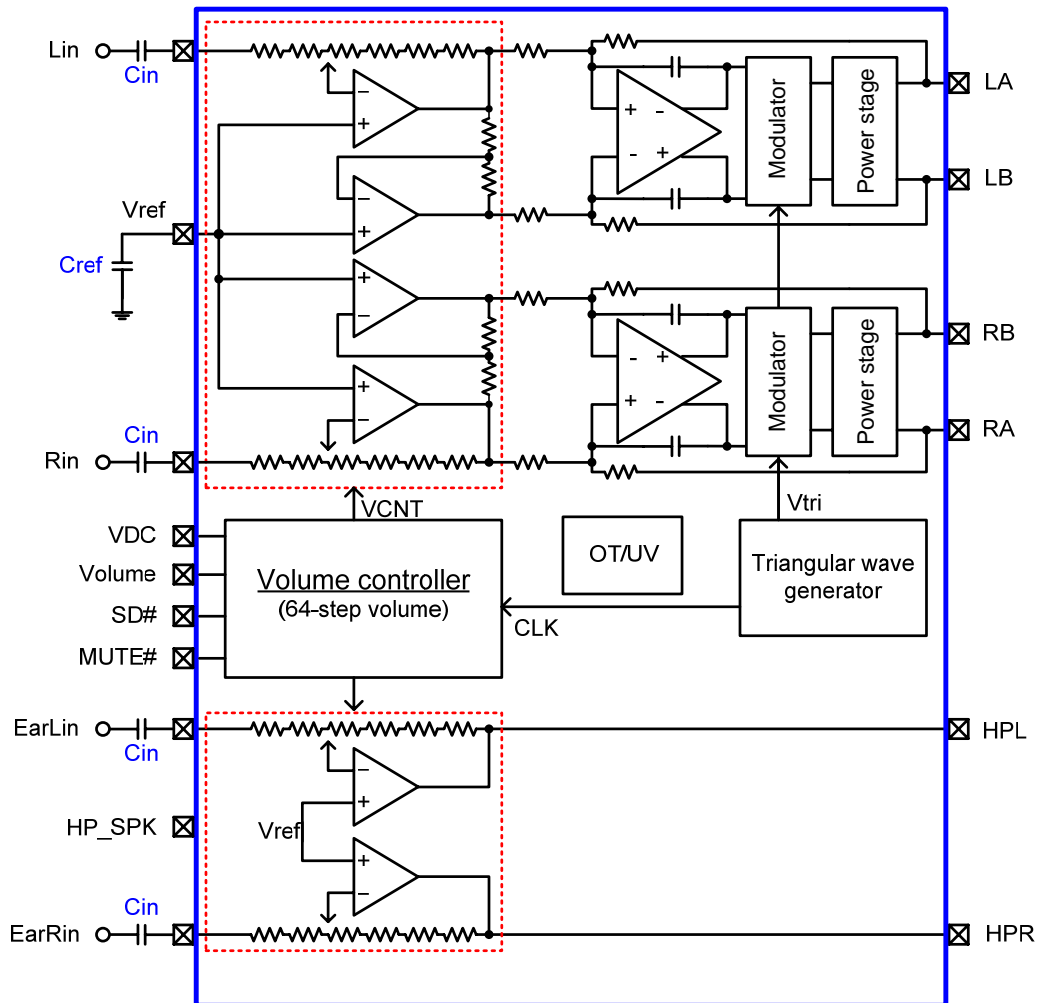
Pin Assignments



Pin Description

NAME	TYP	DESCRIPTION	CHARACTERISTIC	
1	LA	O	Speaker driver_Left (+)	
2	PGNDL	G	Power ground_Left	
3	PGNDL	G	Power ground_Left	
4	LB	O	Speaker driver_Left (-)	
5	PVDDL	P	Power supply_Left	
6	MUTE#	I	Mute (low active)	Internal pull-up
7	AVDD	P	Analog power supply	
8	INL	I	Single-ended audio input_Left for SPK	
9	EARinL	I	Single-ended audio input_Left for HP	
10	VDC	I	Full scale level for gain control section	Internal pull-up
11	VOLUME	I	Volume level setting by DC voltage	Internal pull-up
12	HPL	O	Headphone driver_Left	
13	HPR	O	Headphone driver_Right	
14	VREF	I	AVDD/2 reference voltage	
15	HP_SPKB	I.	HP or SPK mode selection (1:HP;0:SPK)	Internal pull-down
16	EARinR	I	Single-ended audio input_Right for HP	
17	INR	I	Single-ended audio input_Right for SPK	
18	AGND	G	Analog power ground	
19	SD#	I	Shutdown (low active)	Internal pull-up
20	PVDDR	P	Power supply_Right	
21	RB	O	Speaker driver_Right (-)	
22	PGNDR	G	Power ground_Right	
23	PGNDR	G	Power ground_Right	
24	RA	O	Speaker driver_Right (+)	

Functional Block Diagram



Available Package

Package Type	Device No.	θ_{ja} (°C/W)	θ_{jc} (°C/W)
SSOP-24	AD52652	90	17

Note 1: θ_{ja} is measured on a room temperature ($T_A=25^\circ\text{C}$), natural convection environment test board, which is constructed with a thermally efficient, 2-layers PCB. The measurement is tested using the JEDEC51-3 thermal measurement standard.

Note 2: θ_{jc} represents the heat resistance for the heat flow between the chip and the package's top surface.

Marking Information

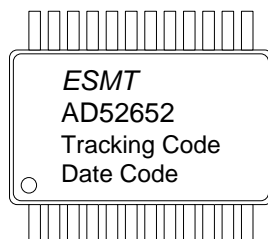
AD52652

Line 1 : LOGO

Line 2 : Product no.

Line 3 : Tracking Code

Line 4 : Date Code



Absolute Maximum Ratings

SYMBOL	PARAMETER	MIN	MAX	UNIT
AVDD	Power supply for lower power analog circuits	3.0	6.0	V
PVDDL(R)	Power supply for loudspeaker driver	3.0	6.0	V
	Input voltage	-0.3	AVDD	V
T _{stg}	Storage temperature	-65	150	°C
T _j	Junction temperature	-40	150	°C

Recommended Operating Conditions

SYMBOL	PARAMETER	TYP	UNIT
AVDD	Power supply for lower power analog cells	3.0~5.5	V
PVDDL(R)	Power supply for Driver Stage	3.0~5.5	V
V _{IH}	High-Level Input Voltage	1.2	V
V _{IL}	Low-Level Input Voltage	0.4	V
T _a	Ambient Operating Temperature	-40~85	°C

General Electrical Characteristics

SYMBOL	PARAMETER	CONDITION	MIN	TYP	MAX	UNIT
I _{SD}	Supply current during Shut-down mode	AVDD=PVDDR(L)=VDD=5.0V, SD#=0.4V			1	μA
I _{Q,SPK}	Supply current during SPEAKER mode	AVDD=PVDDR(L)=VDD=5.0V, SD#=MUTE#=5.0V, HP_SPKB=0V		8.5		mA
I _{Q,HP}	Supply current during HEADPHONE mode	AVDD=PVDDR(L)=VDD=5.0V, SD#=MUTE#=HP_SPKB=5.0V		2		mA
I _{MUTE, SPK}	Supply current during MUTE mode	AVDD=PVDDR(L)=VDD=5.0V, SD#=5.0V, MUTE#=0.4V, HP_SPKB=0V		5.1		mA
I _{MUTE, HP}	Supply current during MUTE mode	AVDD=PVDDR(L)=VDD=5.0V, SD#=5.0V, MUTE#=0.4V, HP_SPKB=5.0V		2		mA
V _{offset}	Output offset voltage	Input ac grounded		10	50	mV
	Junction temperature for driver shutdown			160		°C
	Temperature hysteresis for recovery from shutdown			125		°C
f _{sw}	Switching frequency	AVDD=3.0V~5.0V	200	250	330	kHz
R _{on}	Total R _{DS-ON} resistance	AVDD=PVDDR(L)=VDD, I=500mA		400		mΩ
I _{sc}	Loudspeaker short-circuit detect resistance	PVDDR(L)=5V		2.2		A

Electrical Characteristics and Specifications of Loudspeaker Driver

● AVDD=PVDDL=PVDDR=VDD, Gain= Max, Load=8Ω, f_{in}=1 kHz, T_A=25°C (unless otherwise noted)

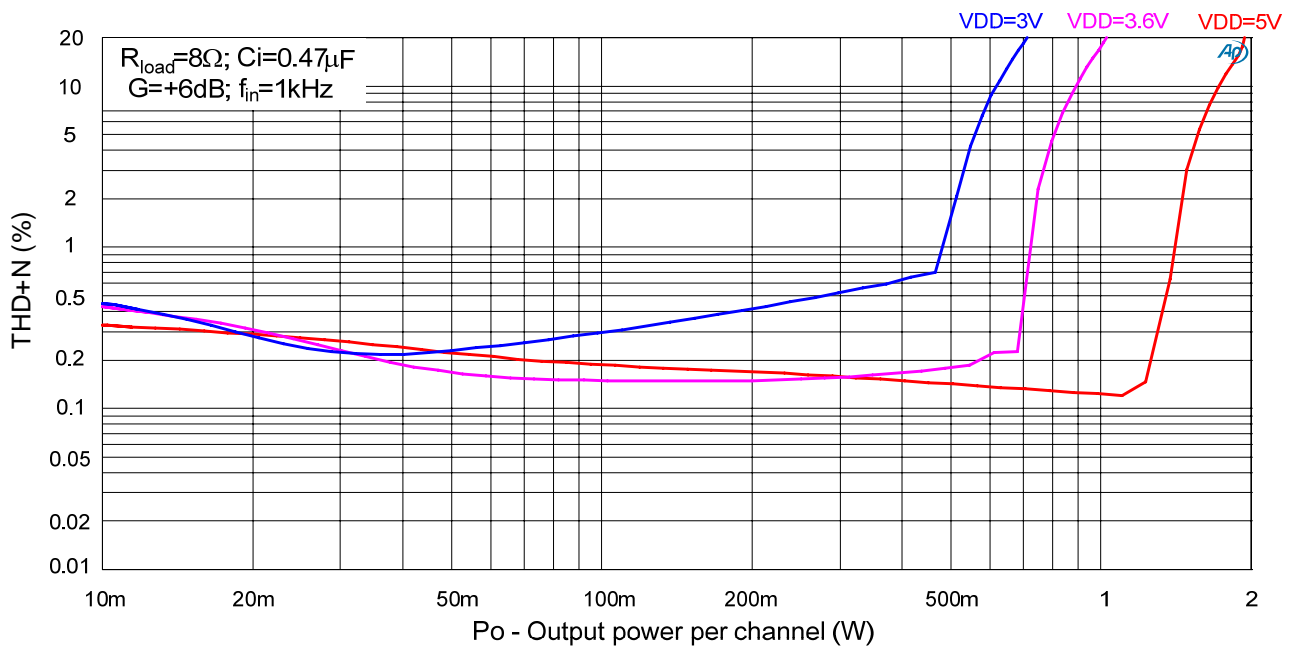
SYMBOL	PARAMETER	CONDITION	MIN	TYP	MAX	UNIT
P _O	RMS Output Power per Channel	VDD=5.0V	THD+N = 10 %		1.75	W
			THD+N = 1 %		1.4	W
		VDD=3.6V	THD+N = 10 %		0.9	W
			THD+N = 1 %		0.7	W
		VDD=3.0V	THD+N = 10 %		0.6	W
			THD+N = 1 %		0.45	W
THD+N	Total Harmonic Distortion plus Noise	VDD=5.0V, Po=1.0W			0.1	%
		VDD=3.6V, Po=0.5W			0.2	%
		VDD=3.0V, Po=0.2W			0.5	%
SNR	Signal to Noise Ratio	VDD=5.0V, Po=1.0W			96	dB
PSRR	Power Supply Rejection Ratio	VDD=5.0V, Gain=Max, Ci=0.47uF, Cref=1uF, V _{ripple} =200mVpp, inputs ac grounded, f=1kHz			-66	dB
Crosstalk	Crosstalk	VDD=5V, f _{in} =1kHz			-100	dB
V _n	Output integrated noise (A-weighted)	VDD=5.0V f _{in} =20Hz ~ 20kHz			80	μV
η	Efficiency	VDD=5V, THD+N=10%			91	%

● AVDD=PVDDL=PVDDR=VDD Gain= Max, Load=4Ω, f_{in}=1 kHz, T_A=25°C (unless otherwise noted)

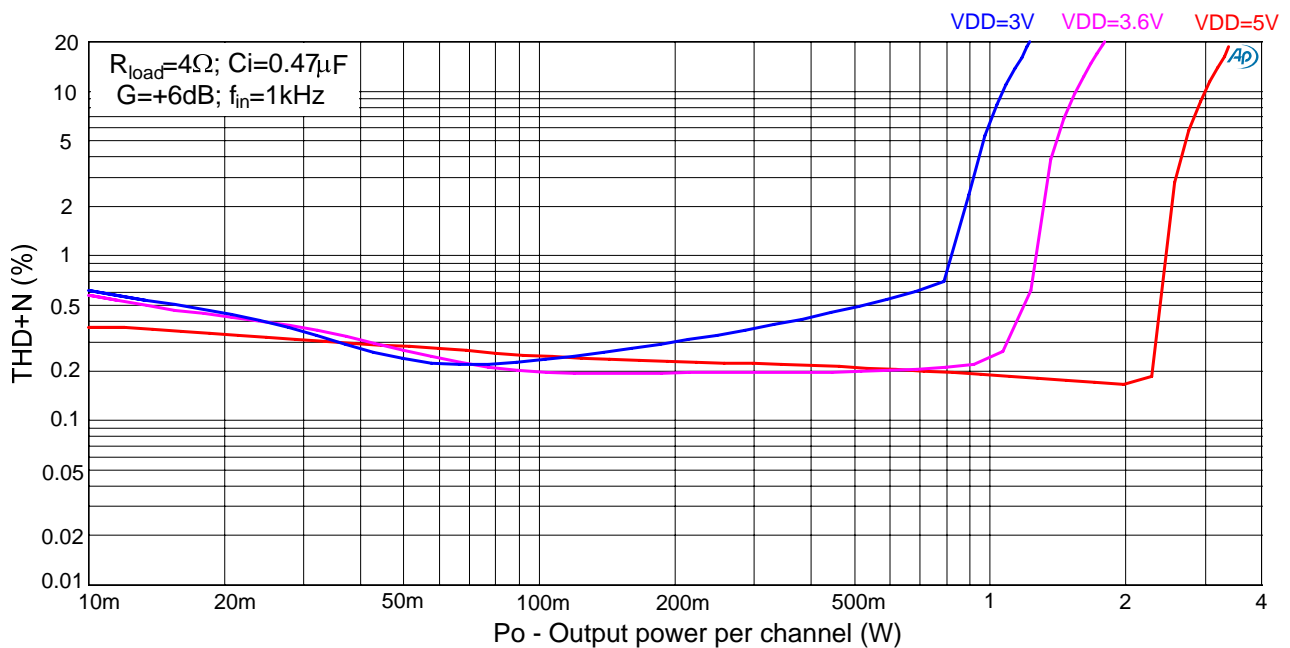
SYMBOL	PARAMETER	CONDITION	MIN	TYP	MAX	UNIT
P _O	RMS Output Power per Channel	VDD=5.0V	THD+N = 10 %		3.0	W
			THD+N = 1 %		2.45	W
		VDD=3.6V	THD+N = 10 %		1.5	W
			THD+N = 1 %		1.2	W
		VDD=3.0V	THD+N = 10 %		1.0	W
			THD+N = 1 %		0.8	W
THD+N	Total Harmonic Distortion plus Noise	VDD=5.0V, Po=1.8W			0.2	%
		VDD=3.6V, Po=0.9W			0.3	%
		VDD=3.0V, Po=0.5W			0.6	%
SNR	Signal to Noise Ratio	VDD=5.0V, Po=1.8W			96	dB
PSRR	Power Supply Rejection Ratio	VDD=5.0V, Gain=Max, Ci=0.47uF, Cref=1uF, V _{ripple} =200mVpp, inputs ac grounded, f=1kHz			-66	dB
Crosstalk	Crosstalk	VDD=5V, f _{in} =1kHz			-100	dB
V _n	Output integrated noise (A-weighted)	VDD=5.0V f _{in} =20Hz ~ 20kHz			80	μV
η	Efficiency	VDD=5V, THD+N=10%			84	%

Typical Characteristics of Loudspeaker Driver

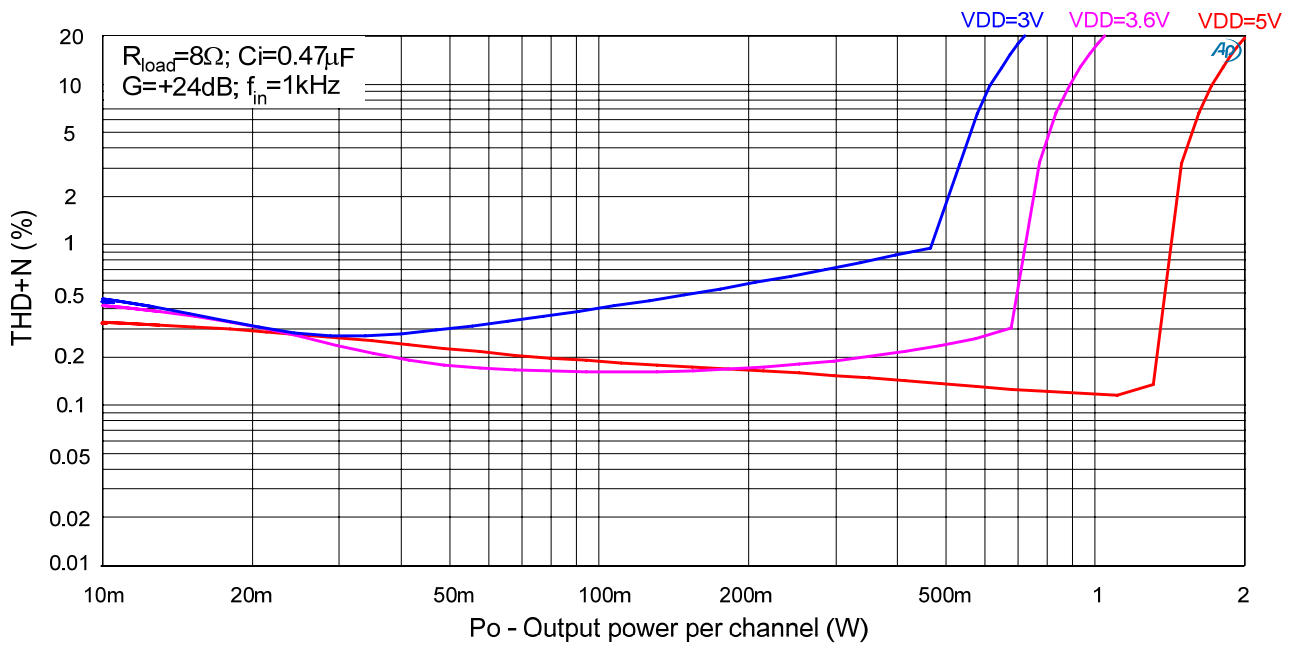
- Total Harmonic Distortion + Noise (THD+N) vs. Output Power (+6dB, 8Ω)



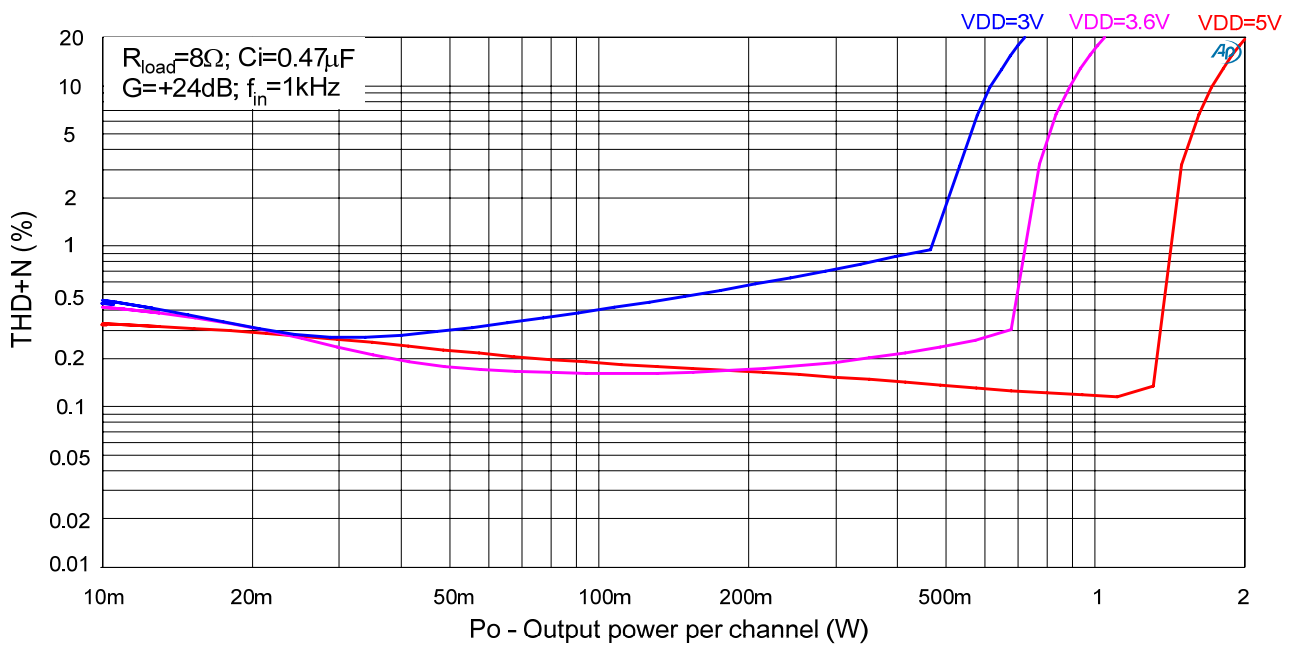
- Total Harmonic Distortion + Noise (THD+N) vs. Output Power (+6dB, 4Ω)



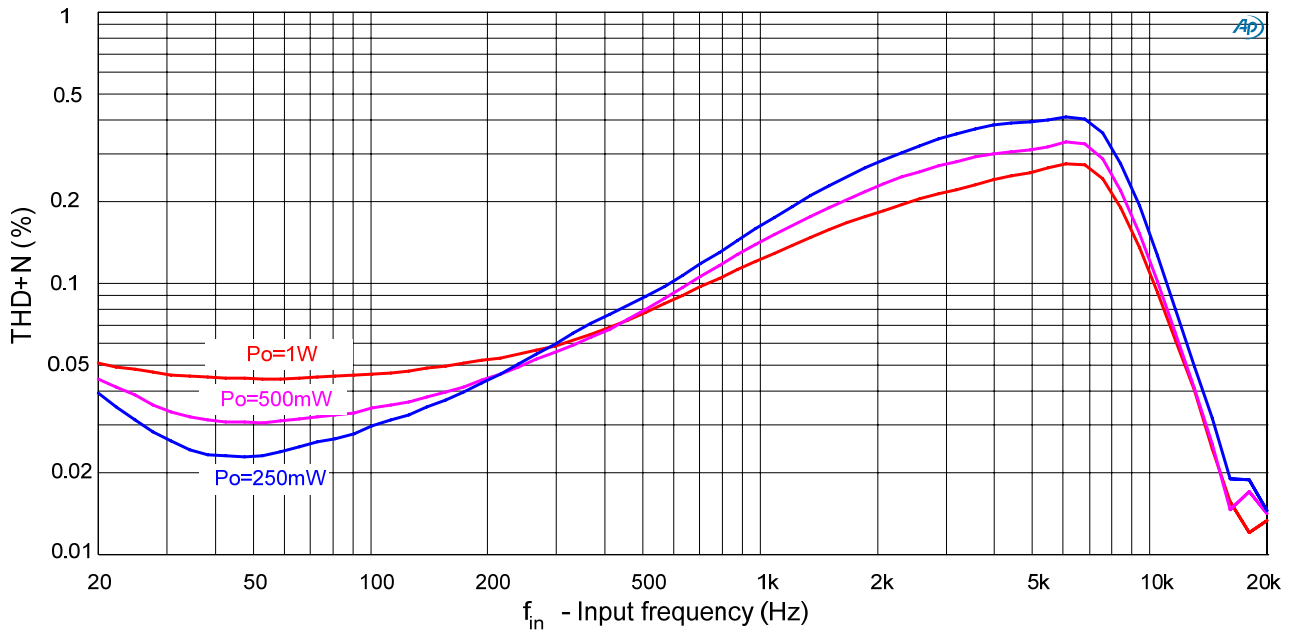
● Total Harmonic Distortion + Noise (THD+N) vs. Output Power (+24dB, 8Ω)



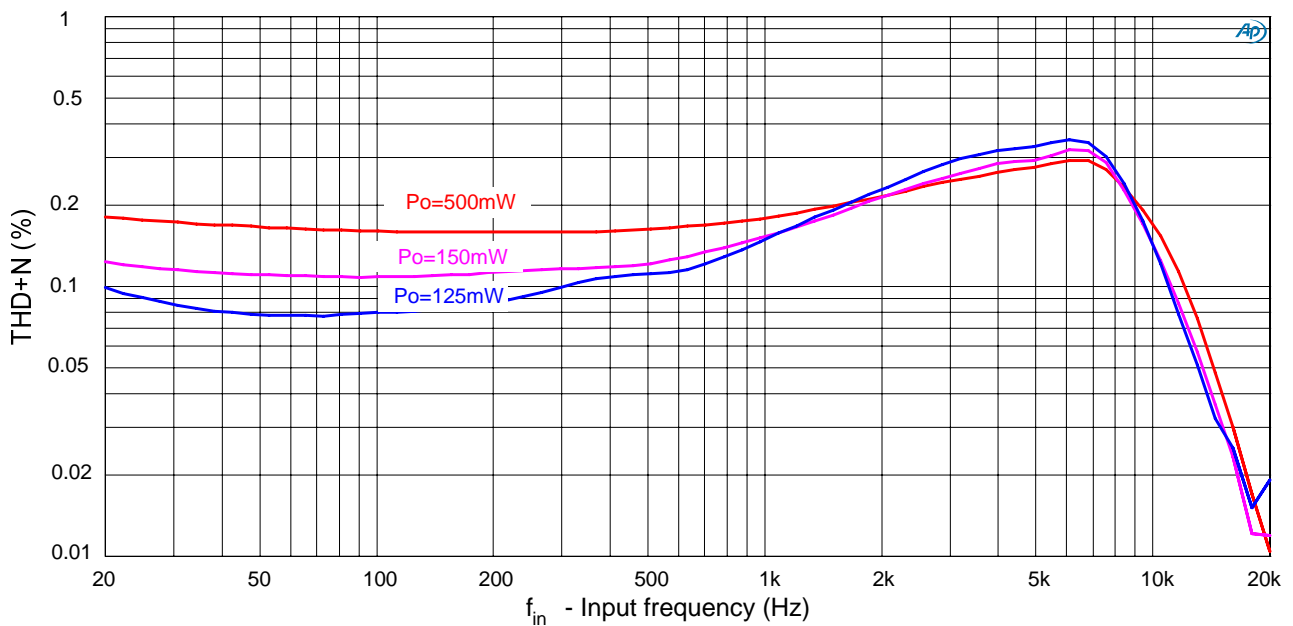
● Total Harmonic Distortion + Noise (THD+N) vs. Output Power (+24dB, 4Ω)



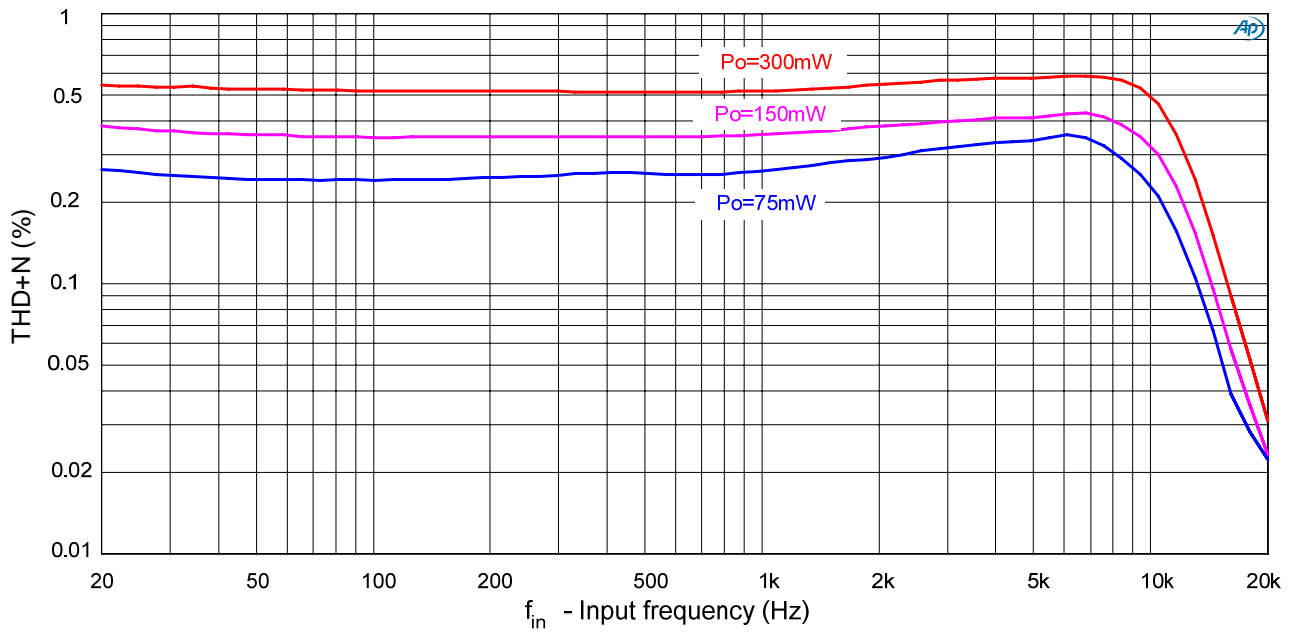
● Total Harmonic Distortion + Noise (THD+N) vs. Signal Frequency (5.0V, 8Ω)



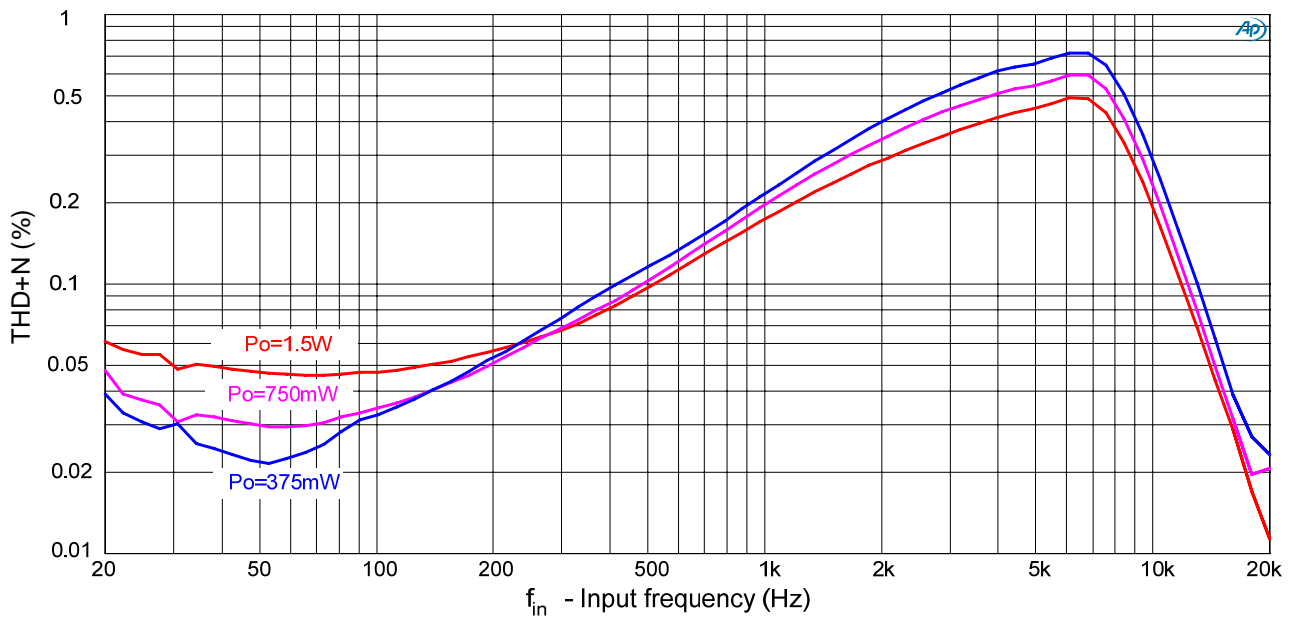
● Total Harmonic Distortion + Noise (THD+N) vs. Signal Frequency (3.6V, 8Ω)



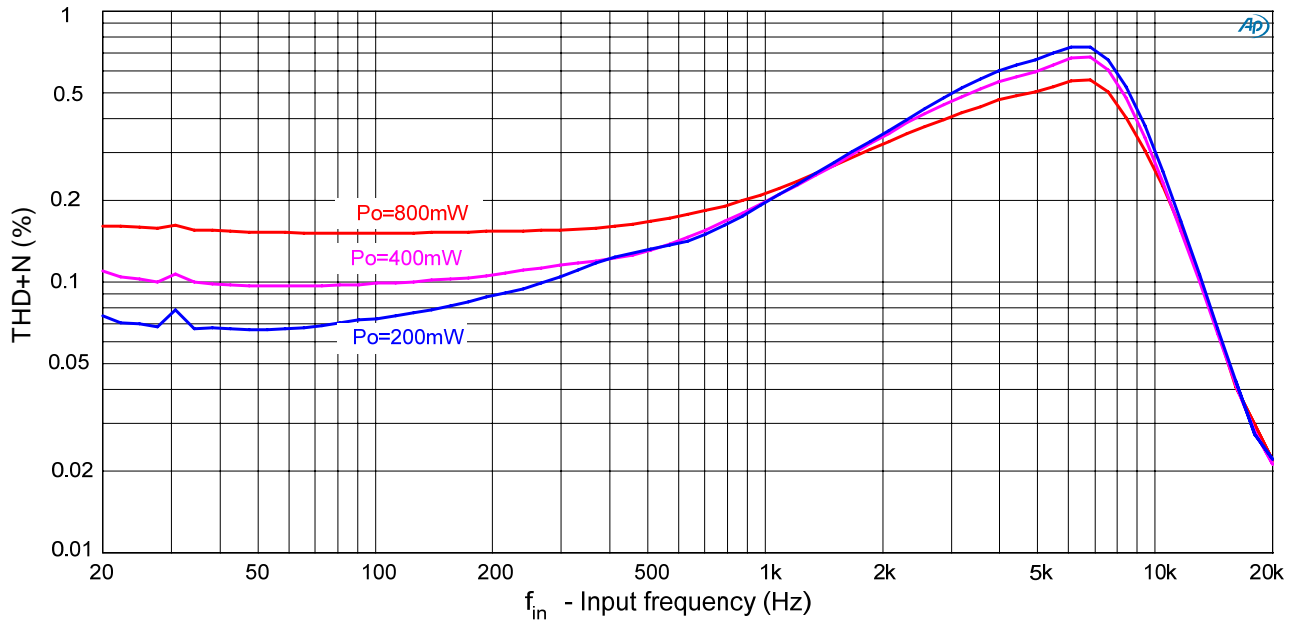
● Total Harmonic Distortion + Noise (THD+N) vs. Signal Frequency (3.0V, 8Ω)



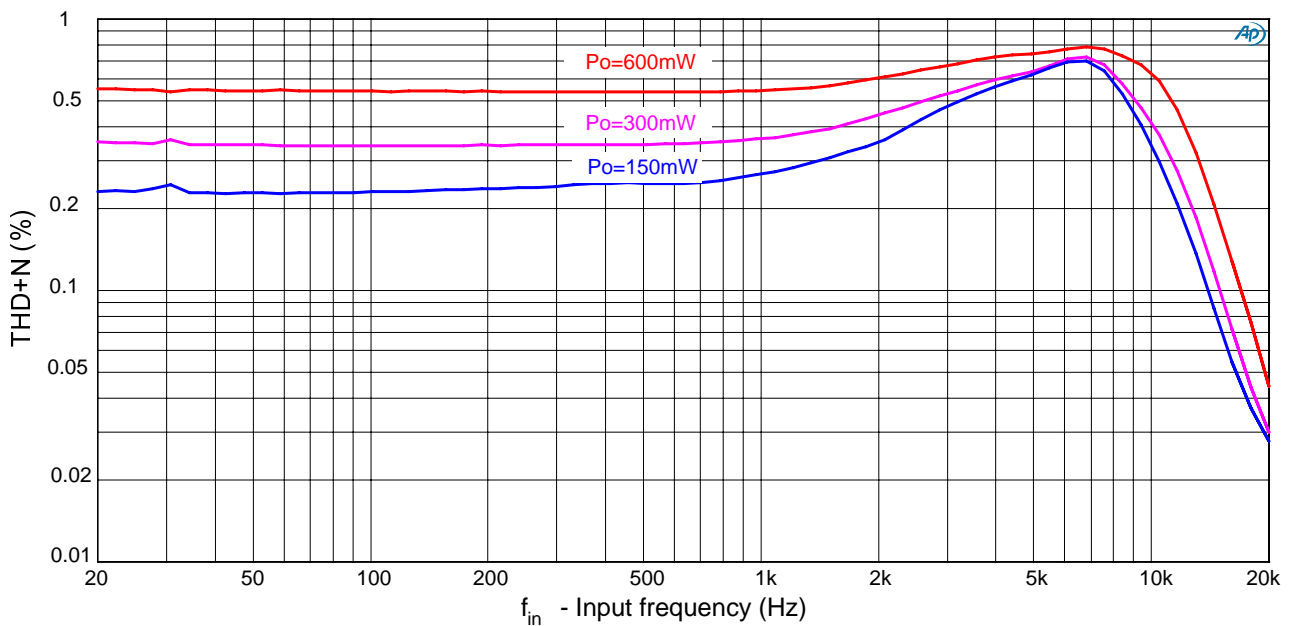
● Total Harmonic Distortion + Noise (THD+N) vs. Signal Frequency (5.0V, 4Ω)



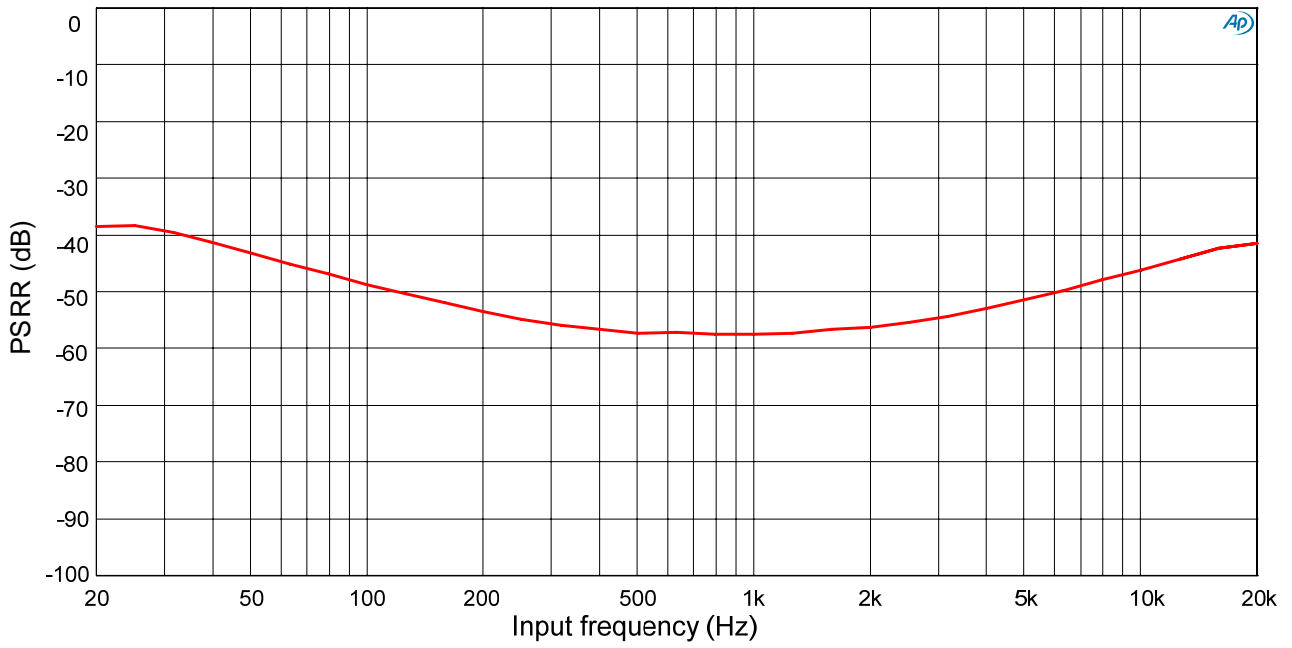
● Total Harmonic Distortion + Noise (THD+N) vs. Signal Frequency (3.6V, 4Ω)



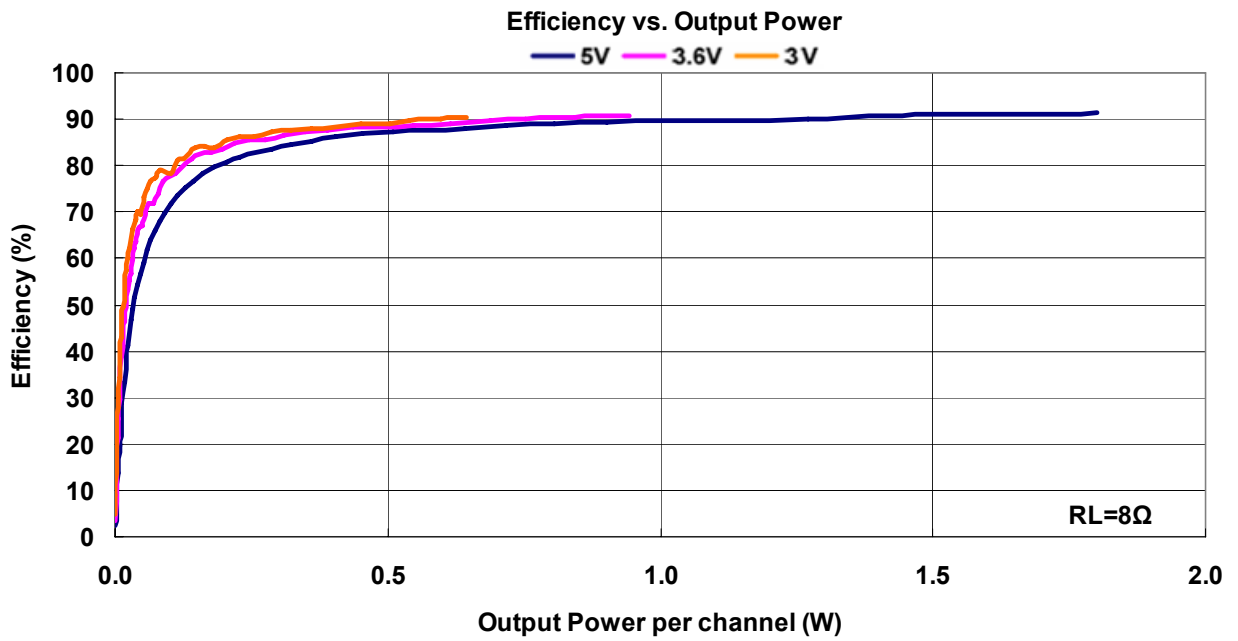
● Total Harmonic Distortion + Noise (THD+N) vs. Signal Frequency (3.0V, 4Ω)



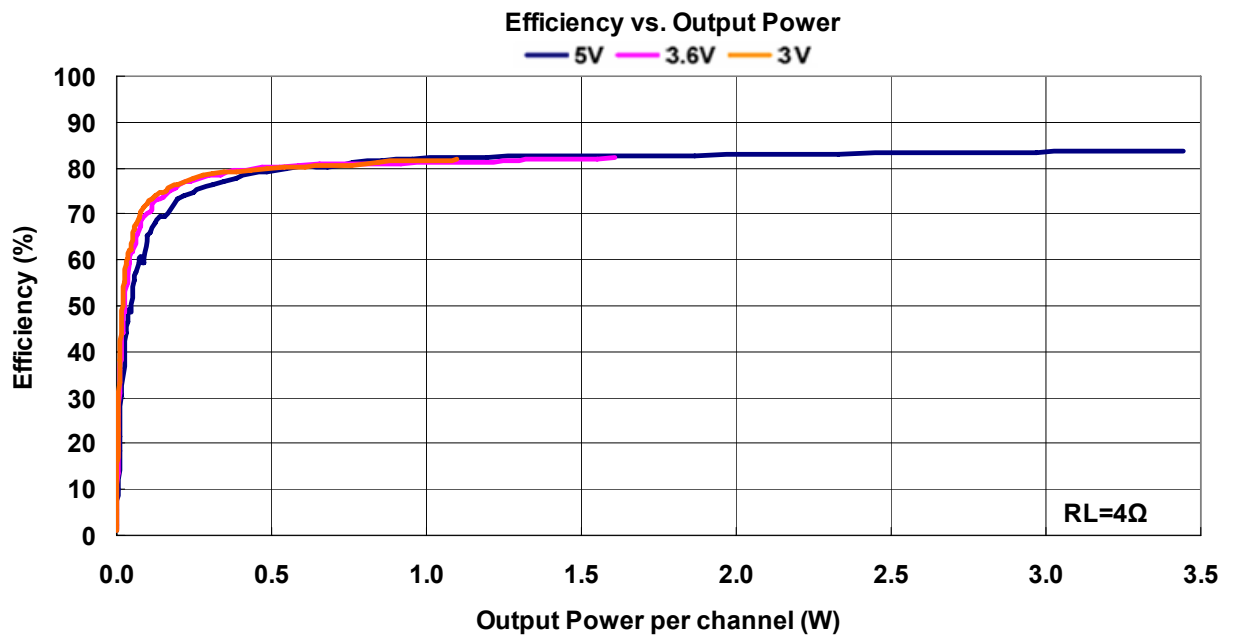
● Power Supply Rejection Ratio vs. Frequency (5V, +6dB)



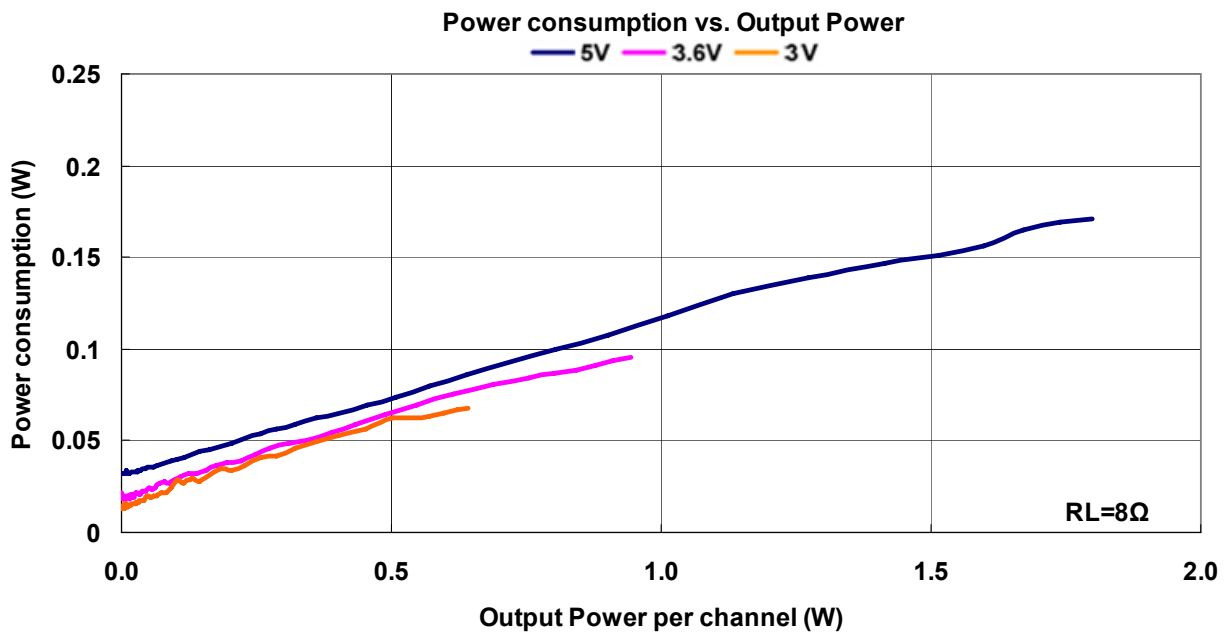
● Efficiency vs. Output Power (8Ω)



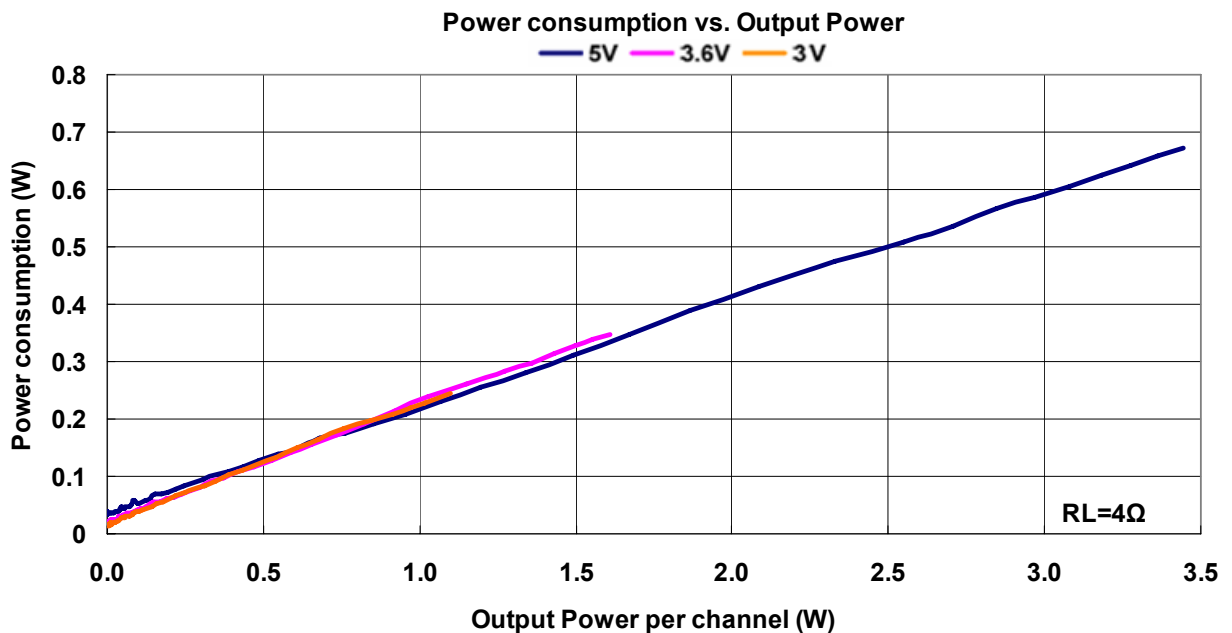
● Efficiency vs. Output Power (4Ω)



● Power Consumption vs. Output Power (8Ω)



● Power Consumption vs. Output Power (4Ω)



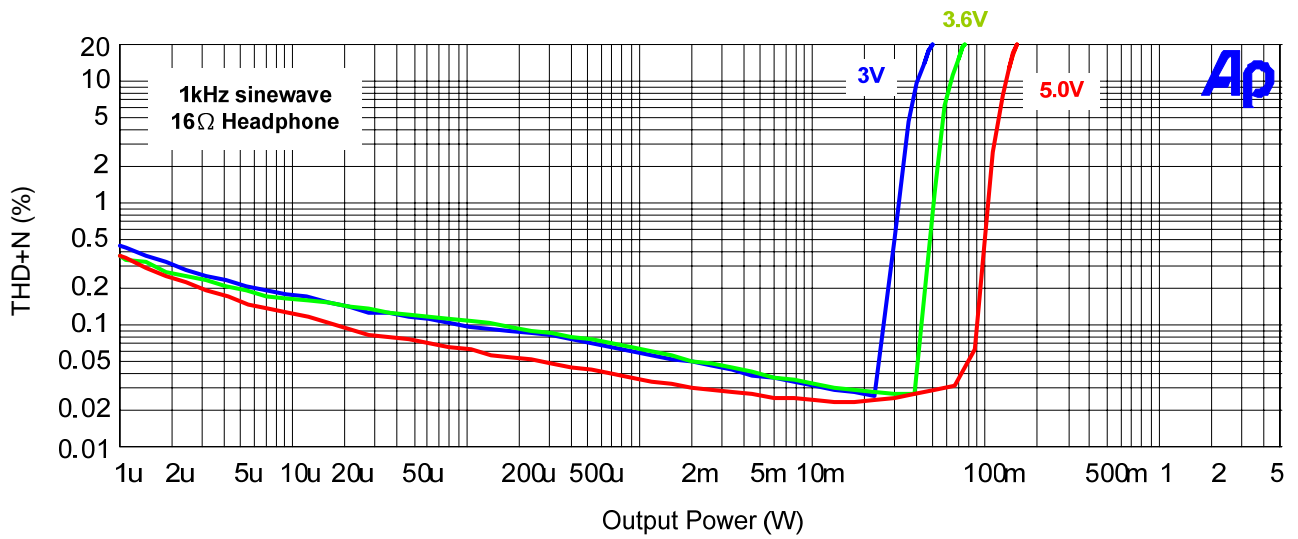
Electrical Characteristics and Specifications of headphone driver

- AVDD=PVDDL=PVDDR=VDD, Gain= Max, Load=32Ω, $f_{in}=1$ kHz, $T_A=25^{\circ}\text{C}$ (unless otherwise noted)

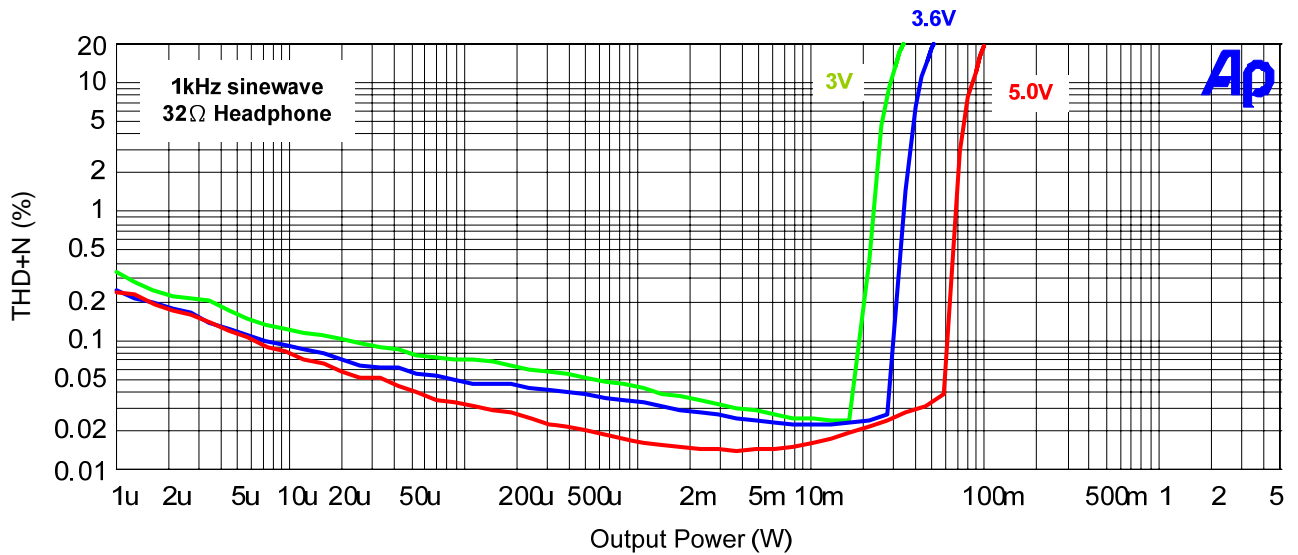
SYMBOL	PARAMETER	CONDITION	MIN	TYP	MAX	UNIT	
P _O	RMS Output Power per Channel	VDD=5.0V	THD+N = 10 %		85		mW
			THD+N = 1 %		65		mW
		VDD=3.6V	THD+N = 10 %		45		mW
			THD+N = 1 %		30		mW
		VDD=3.0V	THD+N = 10 %		30		mW
			THD+N = 1 %		22		mW
THD+N	Total Harmonic Distortion plus Noise	VDD=5.0V, Po=50mW		0.02		%	
		VDD=3.6V, Po=25mW		0.02		%	
		VDD=3.0V, Po=18mW		0.02		%	
SNR	Signal to Noise Ratio	VDD=5.0V, Po=1.8mW		96		dB	
PSRR	Power Supply Rejection Ratio	VDD=5.0V, Gain=Max, Ci=0.47uF, Cref=1uF, V _{ripple} =200mVpp, inputs ac grounded, f=1kHz		-90		dB	
Crosstalk	Crosstalk	VDD=5V, $f_{in}=1$ kHz		-100		dB	
V _n	Output integrated noise (A-weighted)	VDD=5.0V $f_{in}=20\text{Hz} \sim 20\text{kHz}$		40		μV	

Typical Characteristics of of headphone driver

- Total Harmonic Distortion + Noise (THD+N) vs. Output Power (+3.5dB, 16Ω)



- Total Harmonic Distortion + Noise (THD+N) vs. Output Power (+3.5dB, 32Ω)



Operation Descriptions

● Volume control

AD52652 has built-in a 64-steps DC volume controller, and the volume level is set by the VOLUME DC voltage to VDC ratio. To avoid volume level oscillation from one to adjacent one, the hysteresis voltage between the nearby volume levels is designed in AD52652. For example, the volume level changes from LEVEL14 to LEVEL15 when DC voltage applied on VOLUME increases to $25.0 - (25.0 - 21.8) / 4 = 24.2(\%)$ of VDC. And, the volume level drops from LEVEL15 to LEVEL14 when DC voltage applied on VOLUME decreases to $20.4 + (23.6 - 20.4) / 4 = 21.2(\%)$ of VDC. More volume levels, gains, and its DC voltage ratio applied on VOLUME are listed in following table.

Level	SPK Gain(dB)	HP Gain(dB)	Volume (% of VDC)	Level	SPK Gain(dB)	HP Gain(dB)	Volume (% of VDC)	Level	SPK Gain(dB)	HP Gain(dB)	Volume (% of VDC)
0	-60	-94.6	0.0 ~ 4.2	22	7.8	-16.3	31.6 ~ 34.6	43	16.1	-3.3	61.0 ~ 63.8
1	-40	-56.0	1.9 ~ 5.6	23	8.1	-15.7	33.0 ~ 36.0	44	16.5	-2.8	62.4 ~ 65.2
2	-34	-50.2	3.8 ~ 7.0	24	8.5	-15.0	34.4 ~ 37.4	45	16.9	-2.3	63.8 ~ 66.6
3	-28	-40.7	5.2 ~ 8.4	25	8.9	-14.2	35.8 ~ 38.8	46	17.3	-1.8	65.2 ~ 68.0
4	-22	-36.8	6.6 ~ 9.8	26	9.3	-13.4	37.2 ~ 40.2	47	17.7	-1.4	66.6 ~ 69.4
5	-16	-34.2	8.0 ~ 11.2	27	9.7	-12.6	38.6 ~ 41.6	48	18.1	-0.9	68.0 ~ 70.8
6	-10	-32.1	9.4 ~ 12.4	28	10.1	-11.8	40.0 ~ 43.0	49	18.5	-0.5	69.4 ~ 72.2
7	-7.5	-30.4	10.8 ~ 13.8	29	10.5	-11.1	41.4 ~ 44.4	50	18.9	0.0	70.8 ~ 73.6
8	-4.9	-28.1	12.2 ~ 15.2	30	10.9	-10.5	42.8 ~ 45.8	51	19.3	0.5	72.2 ~ 75.0
9	-2.4	-27.0	13.6 ~ 16.6	31	11.3	-9.8	44.2 ~ 47.2	52	19.7	0.9	73.6 ~ 76.4
10	0.1	-25.9	15.0 ~ 18.0	32	11.7	-9.2	45.6 ~ 48.6	53	20.1	1.2	75.0 ~ 77.8
11	1.6	-24.8	16.2 ~ 19.4	33	12.1	-8.6	47.0 ~ 50.0	54	20.5	1.5	76.4 ~ 79.2
12	3.2	-23.8	17.6 ~ 20.8	34	12.5	-8.0	48.4 ~ 51.4	55	20.9	1.8	77.8 ~ 80.6
13	4.1	-22.9	19.0 ~ 22.2	35	12.9	-7.4	49.8 ~ 52.8	56	21.3	2.1	79.2 ~ 82.0
14	4.6	-22.1	20.4 ~ 23.6	36	13.3	-6.8	51.2 ~ 54.2	57	21.7	2.5	80.6 ~ 83.4
15	5	-21.4	21.8 ~ 25.0	37	13.7	-6.3	52.6 ~ 55.6	58	22.1	2.8	82.2 ~ 84.8
16	5.4	-20.6	23.2 ~ 26.4	38	14.1	-5.8	54.0 ~ 57.0	59	22.5	3.1	83.6 ~ 86.2
17	5.8	-20.0	24.6 ~ 27.8	39	14.5	-5.2	55.4 ~ 58.4	60	22.9	3.2	85.0 ~ 87.6
18	6.2	-19.3	26.0 ~ 29.2	40	14.9	-4.7	56.8 ~ 59.8	61	23.3	3.4	86.4 ~ 89.0
19	6.6	-18.5	27.4 ~ 30.6	41	15.3	-4.2	58.2 ~ 61.2	62	23.7	3.6	87.8 ~ 90.2
20	7	-17.7	28.8 ~ 31.8	42	15.7	-3.7	59.6 ~ 62.4	63	24	3.8	> 90.2
21	7.4	-17.0	30.2 ~ 33.2								

● Self-protection circuits (typical values are used below.)

AD52652 has built-in over-temperature, overload and voltage detectors.

- (i) If the internal junction temperature is higher than 160°C, the outputs of loudspeaker drivers will be disabled and at low state. The temperature hysteresis for AD52652 to return to normal operation is about 35°C. The variation of protected temperature is around 10%.
- (ii) AD52652 has built-in overload protection for both right and left channel. To protect loudspeaker drivers from over-current damage when the wires of loudspeaker are shorted to one another, VDD or GND, circuits for the detection of output loading are built in the AD52652. For normal operation, loudspeaker resistance is larger than 3.2Ω is required. Otherwise, overload detectors may activate. Once both loudspeaker drivers will be disabled due to overload, toggle AD52652 SD# down to low and back to high to wake-up AD52652.

Shut-down control (SD#)

During shutdown mode, means SD#=0, AD52652 ceases all internal circuits. To avoid annoying pop during power on/off, well SD# control, like with a power ready signal, is suggested.

- Mute control (MUTE#)

Like SD# mode, AD52652 ceases output driver, but keep part of internal circuit still working. That could provide quick disable and enable power amplifier.

- Headphone and speaker switching

The AD52652 is a stereo class-D audio amplifier with stereo class-AB headphone driver. By setting HP_SPKB pin, AD52652 can switch between loudspeaker and headphone mode. When HP_SPKB pin is pulled high, AD52652 is in headphone mode and loudspeaker drivers are off. When HP_SPKB is low, AD52652 is in loudspeaker mode and headphone drivers are off. There is an internal pull-down design on HP_SPKB pin. With the internal pull-down design, mode switching between headphone and loudspeaker will be automatic when headphone is plugged in or pulled out the headphone jack.

Application information

● Input capacitors (C_{in})

The performance at low frequency (bass) is affected by the corner frequency (f_c) of the high-pass filter composed of input resistors (R_{in}) and input capacitors (C_{in}), determined in equation (a). And, the resistance of input resistors is different at different volume gain. But there is 20% variation in input resistance from 20% process variation in actual resistance of the input resistors. Typically, a 0.47 μ F or 1 μ F ceramic capacitor is suggested.

$$f_c = \frac{1}{2\pi R_{in} C_{in}} \text{ (Hz)} \dots\dots\dots (a)$$

Loudspeaker	
Gain (dB)	Rin (ohm)
24	42k
18	73k
12	115k
6	160k

Headphone	
Gain (dB)	Rin (ohm)
3.8	40k
-5.8	68k
-11.8	82k
-17.7	92k

● Capacitor on Vref (C_{Vref})

In order to reduce low-frequency noise produced by power supply, the capacitor (C_{Vref}) on Vref, which is the mid-rail voltage of AVDD, is necessary. It is also good for PSRR. And, to have less annoying pop, the recommended C_{Vref} is the same with C_{in} .

● Decoupling capacitor (C_{byp} and C_{bulk})

Because of the power loss on the trace, which is between the device and decoupling capacitor, the decoupling capacitor should be placed as close to the device PVDDL (PVDDR) and PGNDL (PGNDR) to reduce any parasitic resistor or inductor between them. And, a low ESR ceramic capacitor (C_{byp}), typically 1 μ F, is suggested for high frequency transients and as close to AD52652 as possible. For filtering audio band noise signal, a 10 μ F or greater capacitor (C_{bulk}) (tantalum or electrolytic type) is suggested.

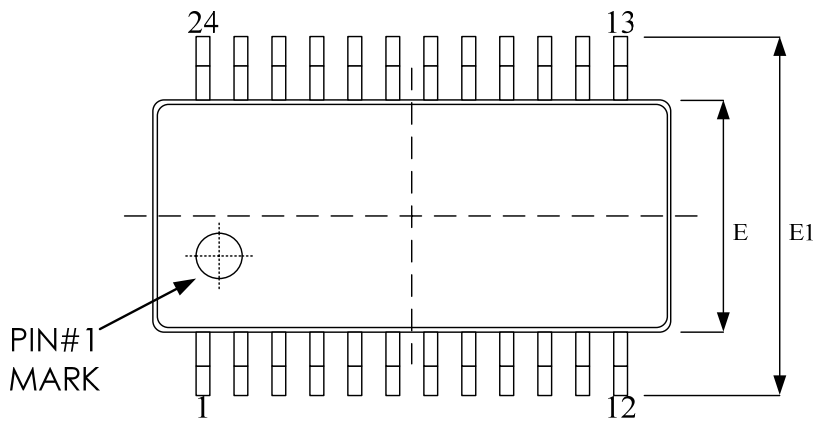
● Headphone DC decoupling capacitors (C_{hp})

The DC decoupling capacitors (C_{hp}) between headphone and HPL/HPR pins are used to remove the DC voltage on the headphone from HPL/HPR. The high pass filter, which is composed of the headphone resistance and the DC decoupling capacitor, attenuates the low frequency audio performance. For 16 Ω headphone, the electrolytic or tantalum capacitor with 100 μ F or greater is suggested. The relationship between f_{hc} , R_{hp} and C_{hp} is shown in the below equation (b).

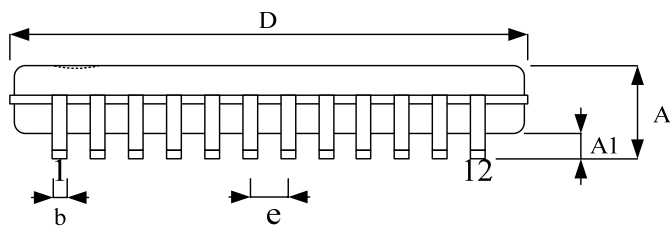
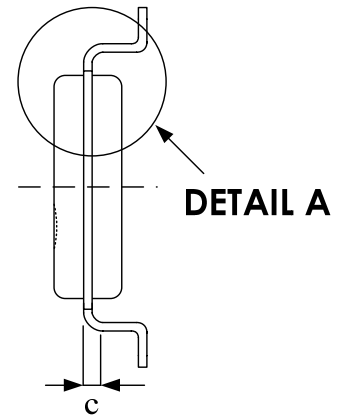
$$f_{hc} = \frac{1}{2\pi R_{hp} C_{hp}} \text{ (Hz)} \dots\dots\dots (b)$$

Package Dimensions

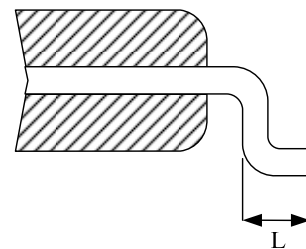
- SSOP 24 (150mil)



TOP VIEW



SIDE VIEW



DETAIL A

Symbol	Dimension in mm	
	Min	Max
A	1.35	1.75
A1	0.10	0.25
b	0.20	0.31
c	0.18	0.25
D	8.53	8.74
E	3.80	4.00
E1	5.80	6.20
e	0.635 BSC	
L	0.38	1.27

Revision History

Revision	Date	Description
0.1	2012.07.04	Original
0.2	2013.12.10	1) Remove EMP logo. 2) Change operating voltage from 3.0~5.0V to 3.0~5.5V. 3) Change AMR voltage from 5.5V to 6.0V. 4) Modify Package Dimensions.
1.0	2015.02.25	Remove "Preliminary"
1.1	2015.04.01	Modify package dimensions
1.2	2016.01.29	1) Replace T_a (Ambient Operating Temperature) by T_j (Junction temperature) in Absolute Maximum Ratings. 2) Change Ambient operating temperature from 0~70°C to -40~85°C. 3) Modify the Description and Volume Table of Volume Control
1.3	2016.05.13	Modify the Description of Input capacitors (C_{in}) in Application Information.

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